

## T500D226K035AG6310

T500, Tantalum, MnO<sub>2</sub> Tantalum, High Temperature, 22 uF, 10%, 35 VDC, SMD, MnO<sub>2</sub>, Molded, High Temperature, 200C, N/A, 700 mOhms, 7343, Height Max = 3.1mm

CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



Click [here](#) for the 3D model.

### Dimensions

Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

### General Information

Series	T500
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, MnO <sub>2</sub> , Molded, High Temperature, 200C
Features	200C
RoHS	Yes
Termination	Gold
AEC-Q200	No
Shelf Life	156 Weeks
MSL	1

### Specifications

Capacitance	22 uF
Capacitance Tolerance	10%
Voltage DC	35 VDC (85C), 23.1 VDC (125C), 14 VDC (200C)
Temperature Range	-55/+200°C
Rated Temperature	85°C
Humidity	85C, 85% RH, 0 V, 1000 Hours
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
Resistance	700 mOhms (100kHz 25C)
Ripple Current	460 mA (rms, 100kHz 25C), 184 mA (rms, 100kHz 125C), 46 mA (rms, 100kHz 200C)
Leakage Current	7.7 uA (5min 25°C)

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

单击下面可查看定价，库存，交付和生命周期等信息

[>>KEMET\(基美\)](#)